

## OSG60R070xF\_Datasheet

GreenMOS™

Green  
PRODUCT

RoHS  
compliant

# Enhancement Mode N-Channel Power MOSFET

### Features

- ◆ Low  $R_{DS(on)}$  & FOM
- ◆ Excellent low switching loss
- ◆ Excellent stability and uniformity
- ◆ Easy to drive

### Applications

- ◆ PC power
- ◆ Server power supply
- ◆ Telecom
- ◆ Solar invertor
- ◆ Super charger for automobiles



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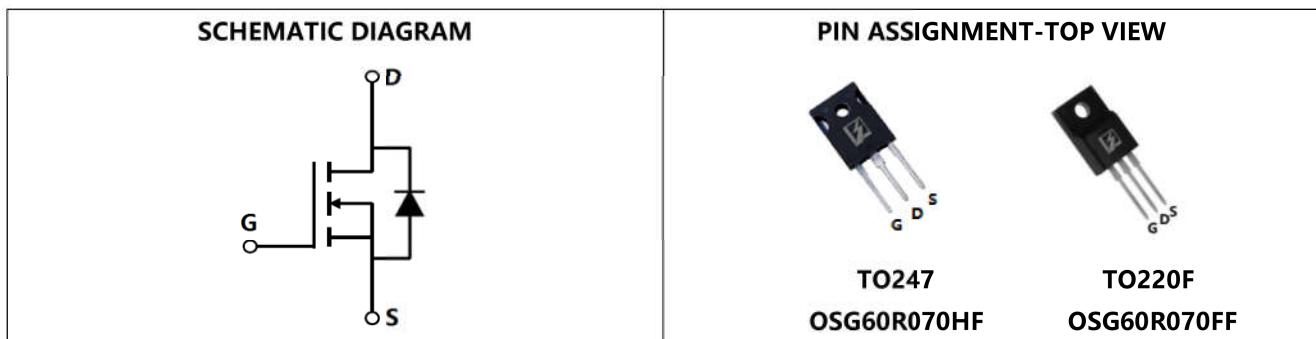
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## ■ General Description

OSG60R070xF use advanced GreenMOS™ technology to provide low  $R_{DS(ON)}$ , low gate charge, fast switching and excellent avalanche characteristics. This device is suitable for telecom and super charger applications.

◆ $V_{DS}$ , min@ $T_{jmax}$	650 V
◆ $I_D$ , pulse	141 A
◆ $R_{DS(ON)}$ , max @ $V_{GS}=10$ V	70 mΩ
◆ $Q_g$	47 nC

## ■ Schematic and Package Information



## ■ Absolute Maximum Ratings at $T_j=25^\circ\text{C}$ unless otherwise noted

PARAMETER	SYMBOL	VALUE	UNIT
Drain source voltage	$V_{DS}$	600	V
Gate source voltage	$V_{GS}$	$\pm 30$	V
Continuous drain current <sup>1)</sup> , $T_C=25^\circ\text{C}$	$I_D$	47	A
Continuous drain current <sup>1)</sup> , $T_C=100^\circ\text{C}$		30	
Pulsed drain current <sup>2)</sup> , $T_C=25^\circ\text{C}$	$I_D$ , pulse	141	A
Power dissipation <sup>3)</sup> for TO247, $T_C=25^\circ\text{C}$	$P_D$	278	W
Power dissipation <sup>3)</sup> for TO220F, $T_C=25^\circ\text{C}$		35	
Single pulsed avalanche energy <sup>5)</sup>	$E_{AS}$	1000	mJ
MOSFET dv/dt ruggedness, $V_{DS}=0\ldots 480$ V	dv/dt	50	V/ns
Reverse diode dv/dt, $V_{DS}=0\ldots 480$ V, $I_{SD} \leq I_D$	dv/dt	15	V/ns
Operation and storage temperature	$T_{stg}$ , $T_j$	-55 to 150	°C

## ■ Thermal Characteristics

PARAMETER	SYMBOL	VALUE		UNIT
		TO247	TO220F	
Thermal resistance, junction-case	$R_{\theta JC}$	0.45	3.6	°C/W
Thermal resistance, junction-ambient <sup>4)</sup>	$R_{\theta JA}$	62	62.5	°C/W

## ■ Electrical Characteristics at $T_j=25$ °C unless otherwise specified

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Drain-source breakdown voltage	$BV_{DSS}$	600			V	$V_{GS}=0$ V, $I_D=1$ mA
		650	716			$V_{GS}=0$ V, $I_D=1$ mA, $T_j=150$ °C
Gate threshold voltage	$V_{GS(th)}$	2		4	V	$V_{DS}=V_{GS}$ , $I_D=1$ mA
Drain-source on-state resistance	$R_{DS(ON)}$		0.060	0.070	Ω	$V_{GS}=10$ V, $I_D=23.5$ A
			0.14			$V_{GS}=10$ V, $I_D=23.5$ A, $T_j=150$ °C
Gate-source leakage current	$I_{GSS}$			100	nA	$V_{GS}=30$ V
				-100		$V_{GS}=-30$ V
Drain-source leakage current	$I_{DSS}$			1	μA	$V_{DS}=600$ V, $V_{GS}=0$ V

## ■ Dynamic Characteristics

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Input capacitance	$C_{iss}$		2933		pF	$V_{GS}=0$ V, $V_{DS}=50$ V, $f=1$ MHz
Output capacitance	$C_{oss}$		350.1		pF	
Reverse transfer capacitance	$C_{rss}$		7.04		pF	
Turn-on delay time	$t_{d(on)}$		66.8		ns	$V_{GS}=10$ V, $V_{DS}=400$ V, $R_G=25$ Ω, $I_D=25$ A
Rise time	$t_r$		76.2		ns	
Turn-off delay time	$t_{d(off)}$		138.7		ns	
Fall time	$t_f$		67.9		ns	



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## ■ Gate Charge Characteristics

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Total gate charge	$Q_g$		47		nC	$I_D=25\text{ A}$ , $V_{DS}=400\text{ V}$ , $V_{GS}=10\text{ V}$
Gate-source charge	$Q_{gs}$		12.2		nC	
Gate-drain charge	$Q_{gd}$		17.4		nC	
Gate plateau voltage	$V_{plateau}$		5.6		V	

## ■ Body Diode Characteristics

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Diode forward current	$I_S$			47	A	$V_{GS} < V_{th}$
Pulsed source current	$I_{SP}$			141		
Diode forward voltage	$V_{SD}$			1.4	V	$I_S=47\text{ A}$ , $V_{GS}=0\text{ V}$
Reverse recovery time	$t_{rr}$		454.8		ns	$I_S=25\text{ A}$ , $di/dt=100\text{ A}/\mu\text{s}$
Reverse recovery charge	$Q_{rr}$		7.9		$\mu\text{C}$	
Peak reverse recovery current	$I_{rrm}$		32.1		A	

## ■ Note

- 1) Calculated continuous current based on maximum allowable junction temperature.
- 2) Repetitive rating; pulse width limited by max. junction temperature.
- 3)  $P_d$  is based on max. junction temperature, using junction-case thermal resistance.
- 4) The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with  $T_a=25\text{ }^{\circ}\text{C}$ .
- 5)  $V_{DD}=100\text{ V}$ ,  $R_G=25\text{ }\Omega$ ,  $L=40\text{ mH}$ , starting  $T_j=25\text{ }^{\circ}\text{C}$ .



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## ■ Electrical Characteristics Diagrams

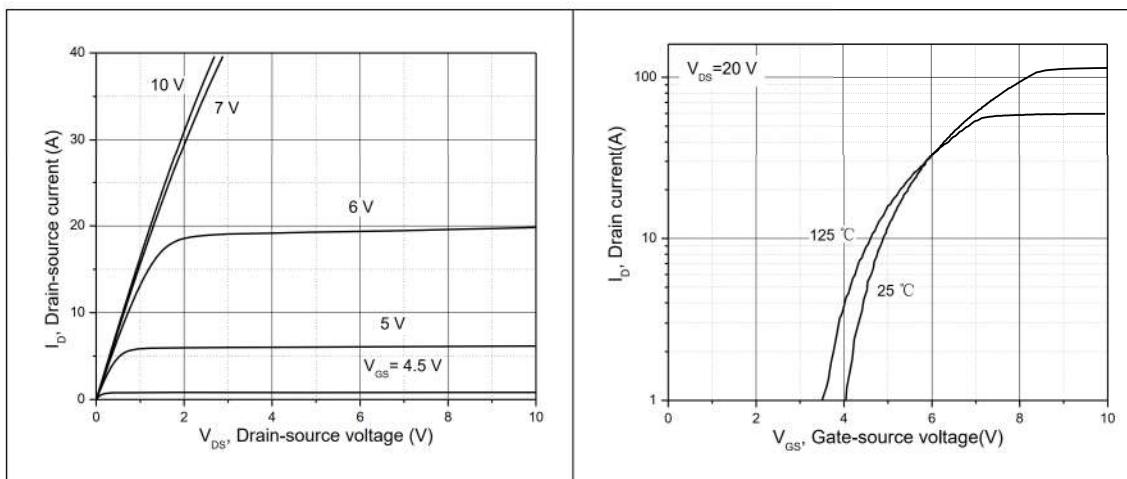


Figure 1, Typ. output characteristics

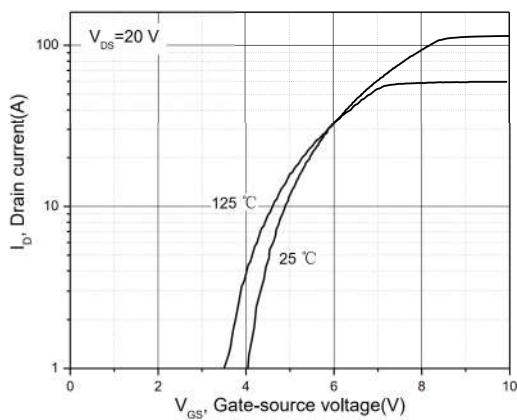


Figure 2, Typ. transfer characteristics

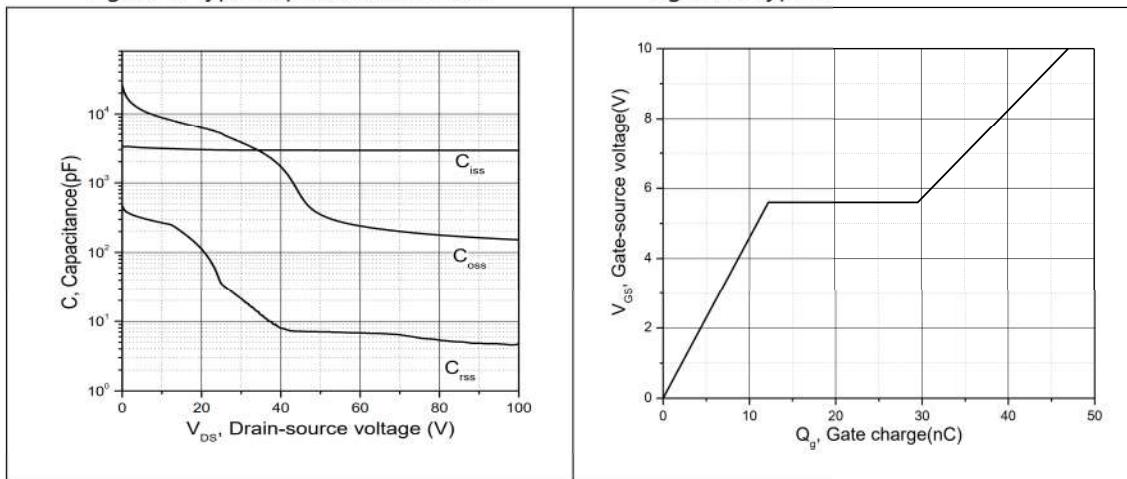


Figure 3, Typ. capacitances

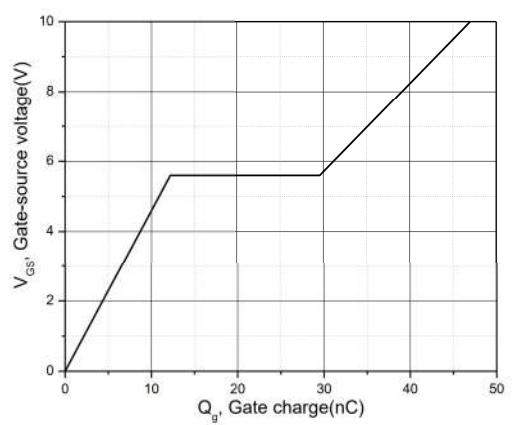


Figure 4, Typ. gate charge

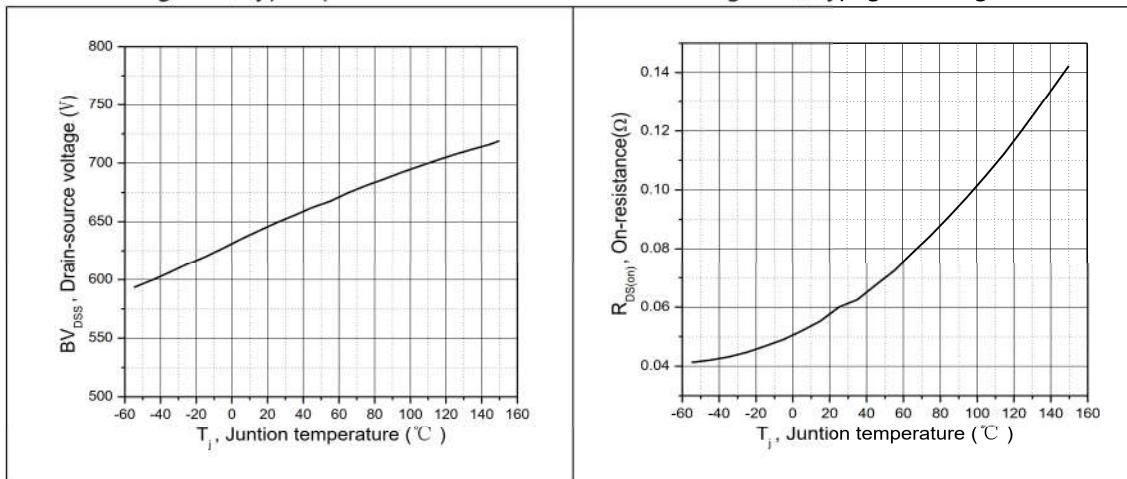


Figure 5, Drain-source breakdown voltage

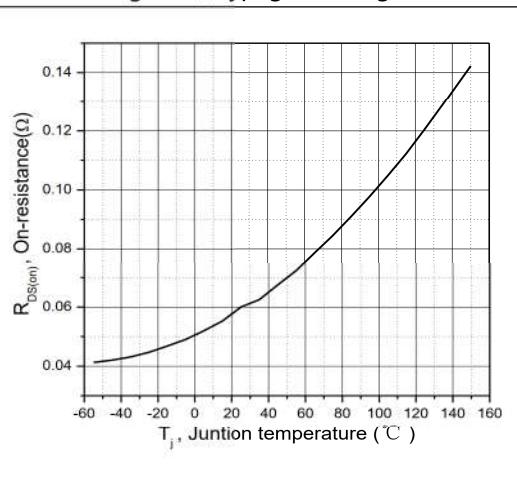


Figure 6, Drain-source on-state resistance



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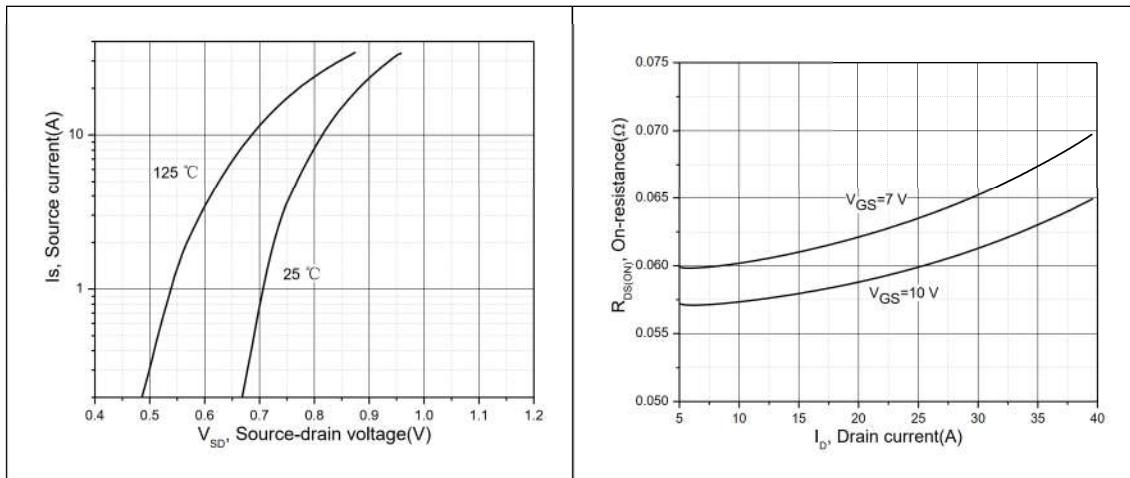


Figure 7, Forward characteristic of body diode

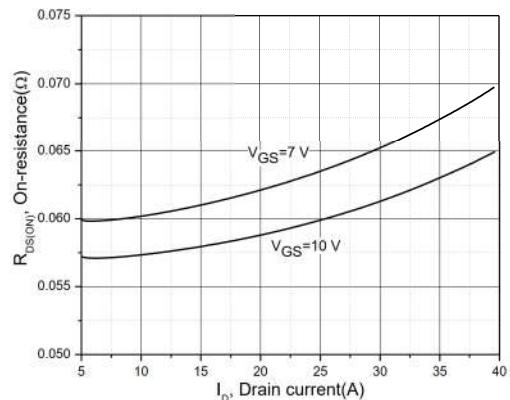


Figure 8, Drain-source on-state resistance

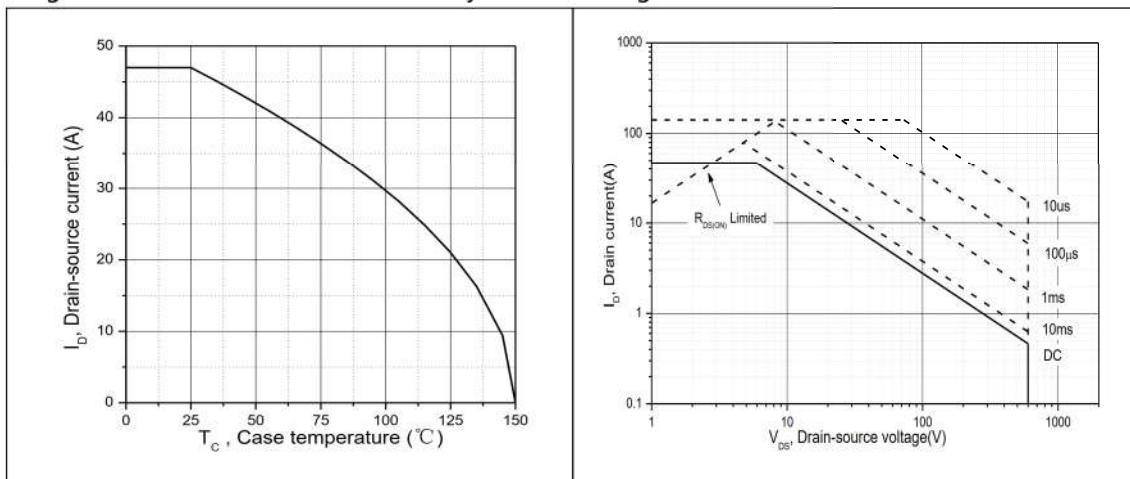


Figure 9, Drain current

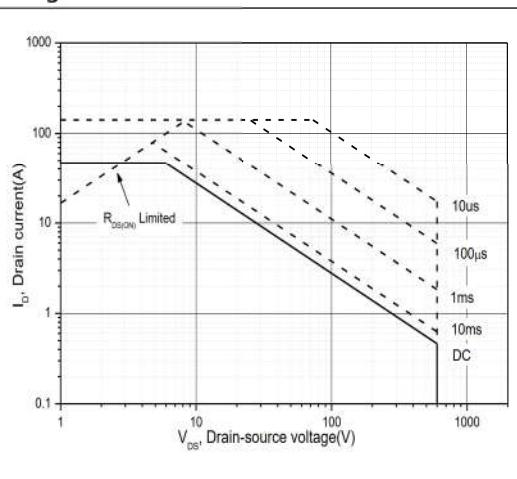


Figure 10, Safe operation area for TO247  
 $T_C=25^\circ\text{C}$

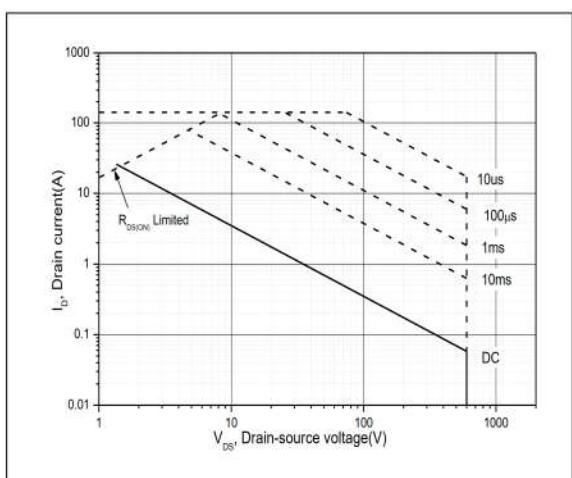


Figure 11, Safe operation area for TO220F  
 $T_C=25^\circ\text{C}$

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## ■ Test circuits and waveforms

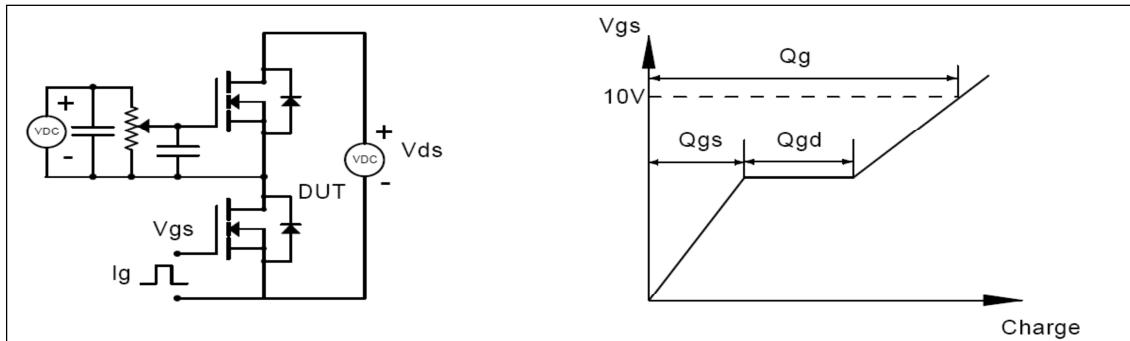


Figure 1, Gate charge test circuit &amp; waveform

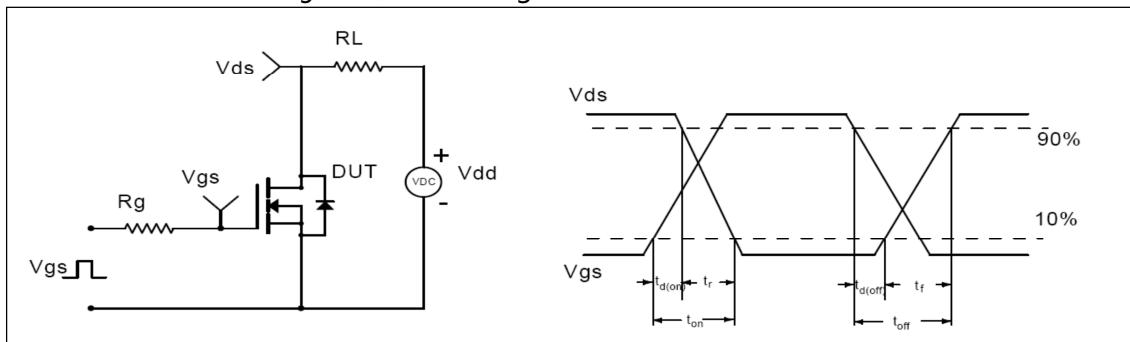


Figure 2, Switching time test circuit &amp; waveforms

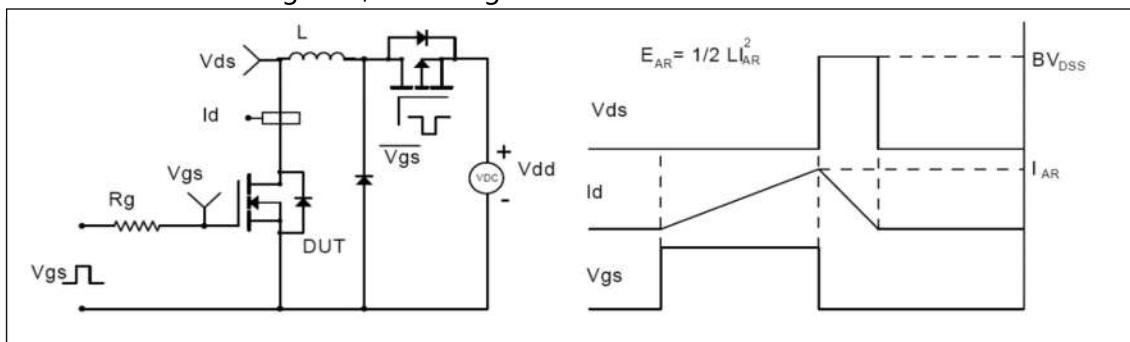


Figure 3, Unclamped inductive switching (UIS) test circuit &amp; waveforms

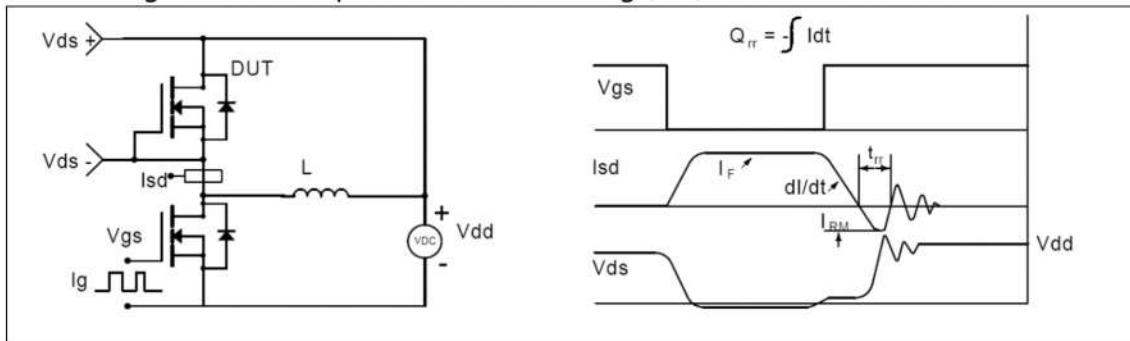
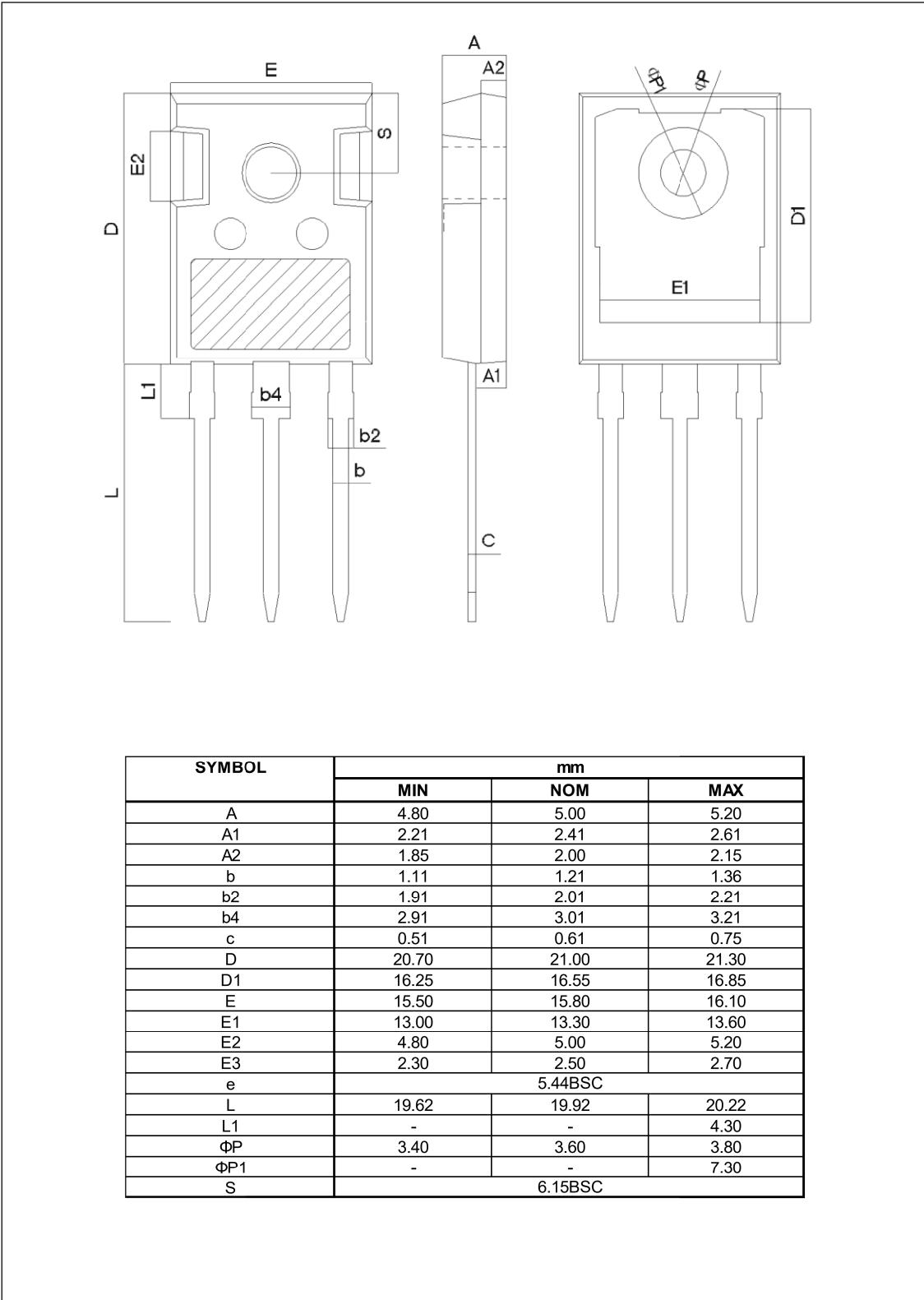


Figure 4, Diode reverse recovery test circuit &amp; waveforms

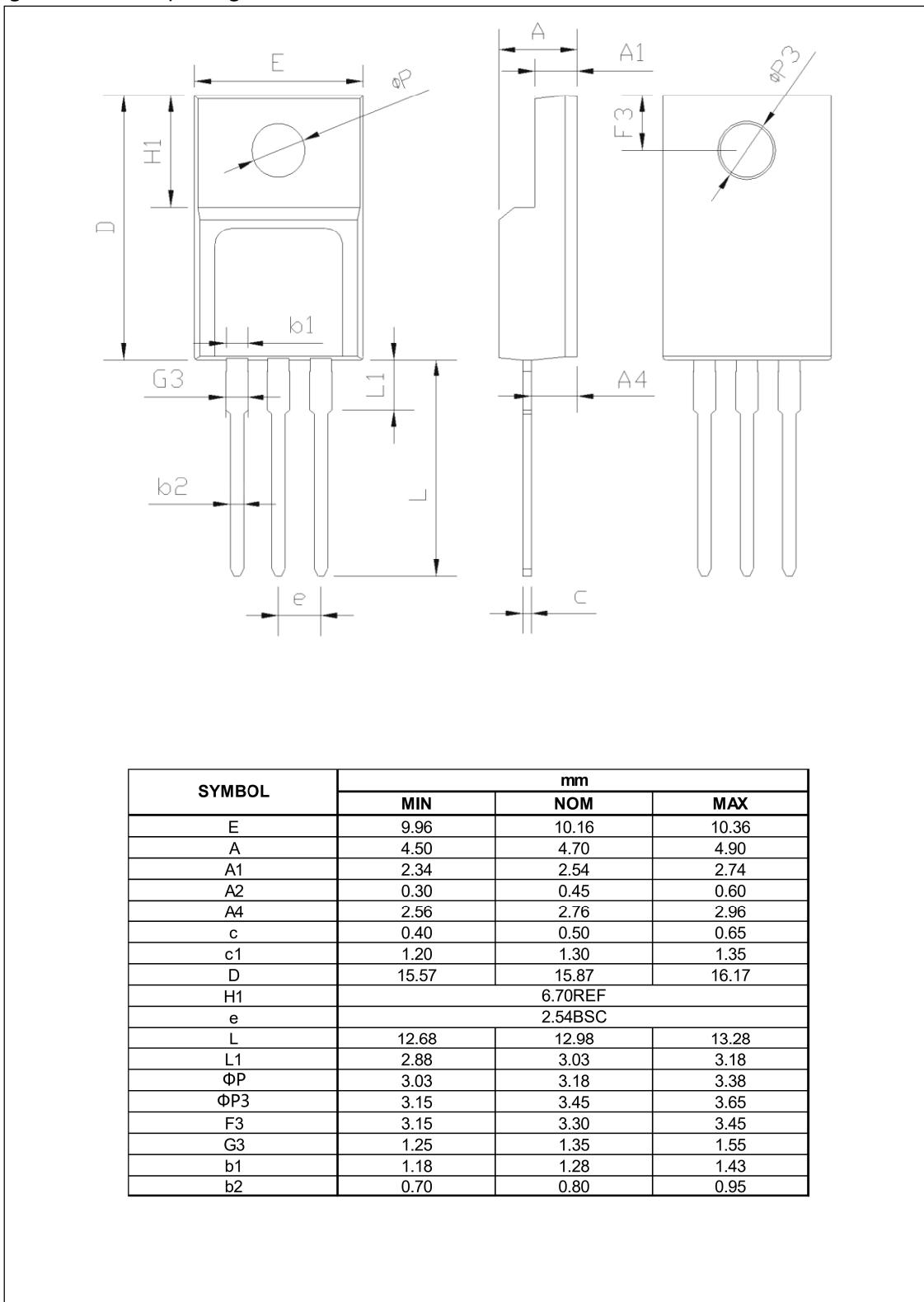
## ■ Package Information

Figure1, TO247 package outline dimension



## ■ Package Information

Figure2, TO220F package outline dimension



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## ■ Ordering Information

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Package	Units/Tube	Tubes/Inner Box	Units/Inner Box	Inner Box/Carton Box	Units/Carton Box
TO220F	50	20	1000	6	6000
TO247	30	11	330	6	1980

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## ■ Product Information

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Product	Package	Pb Free	RoHS	Halogen Free
OSG60R070FF	TO220F	yes	yes	yes
OSG60R070HF	TO247	yes	yes	yes



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